

Hailong Zhou

List of Publications by Year in descending order

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31
papers

7,764
citations

186265

28
h-index

395702

33
g-index

33
all docs

33
docs citations

33
times ranked

12511
citing authors

#	ARTICLE	IF	CITATIONS
1	Highly efficient gate-tunable photocurrent generation in vertical heterostructures of layered materials. <i>Nature Nanotechnology</i> , 2013, 8, 952-958.	31.5	1,017
2	Electroluminescence and Photocurrent Generation from Atomically Sharp WSe ₂ /MoS ₂ Heterojunction <i>Diodes</i> . <i>Nano Letters</i> , 2014, 14, 5590-5597.	9.1	937
3	Vertically stacked multi-heterostructures of layered materials for logic transistors and complementary inverters. <i>Nature Materials</i> , 2013, 12, 246-252.	27.5	812
4	Graphene: An Emerging Electronic Material. <i>Advanced Materials</i> , 2012, 24, 5782-5825.	21.0	718
5	Plasmon resonance enhanced multicolour photodetection by graphene. <i>Nature Communications</i> , 2011, 2, 579.	12.8	639
6	Chemical vapour deposition growth of large single crystals of monolayer and bilayer graphene. <i>Nature Communications</i> , 2013, 4, 2096.	12.8	493
7	Towards highly efficient photocatalysts using semiconductor nanoarchitectures. <i>Energy and Environmental Science</i> , 2012, 5, 6732.	30.8	400
8	Large Area Growth and Electrical Properties of p-Type WSe ₂ Atomic Layers. <i>Nano Letters</i> , 2015, 15, 709-713.	9.1	372
9	Chemical vapor deposition growth of monolayer MoSe ₂ nanosheets. <i>Nano Research</i> , 2014, 7, 511-517.	10.4	331
10	High-frequency self-aligned graphene transistors with transferred gate stacks. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2012, 109, 11588-11592.	7.1	312
11	High-Yield Chemical Vapor Deposition Growth of High-Quality Large-Area AB-Stacked Bilayer Graphene. <i>ACS Nano</i> , 2012, 6, 8241-8249.	14.6	246
12	Plasmonic and Catalytic AuPd Nanowheels for the Efficient Conversion of Light into Chemical Energy. <i>Angewandte Chemie - International Edition</i> , 2013, 52, 6063-6067.	13.8	152
13	Electric-field-induced strong enhancement of electroluminescence in multilayer molybdenum disulfide. <i>Nature Communications</i> , 2015, 6, 7509.	12.8	132
14	Highly Flexible Electronics from Scalable Vertical Thin Film Transistors. <i>Nano Letters</i> , 2014, 14, 1413-1418.	9.1	131
15	Porous silicon nanowires. <i>Nanoscale</i> , 2011, 3, 4060.	5.6	129
16	Unusually efficient photocurrent extraction in monolayer van der Waals heterostructure by tunnelling through discretized barriers. <i>Nature Communications</i> , 2016, 7, 13278.	12.8	120
17	Growth and Characterization of Wurtzite GaAs Nanowires with Defect-Free Zinc Blende GaAsSb Inserts. <i>Nano Letters</i> , 2008, 8, 4459-4463.	9.1	112
18	Top-Gated Chemical Vapor Deposition Grown Graphene Transistors with Current Saturation. <i>Nano Letters</i> , 2011, 11, 2555-2559.	9.1	88

#	ARTICLE	IF	CITATIONS
19	High-Performance Organic Vertical Thin Film Transistor Using Graphene as a Tunable Contact. ACS Nano, 2015, 9, 11102-11108.	14.6	85
20	A systematic study of atmospheric pressure chemical vapor deposition growth of large-area monolayer graphene. Journal of Materials Chemistry, 2012, 22, 1498-1503.	6.7	76
21	Scalable Fabrication of Self-Aligned Graphene Transistors and Circuits on Glass. Nano Letters, 2012, 12, 2653-2657.	9.1	74
22	Engineering Parallel and Perpendicular Polarized Photoluminescence from a Single Semiconductor Nanowire by Crystal Phase Control. Nano Letters, 2010, 10, 2927-2933.	9.1	56
23	Simplifying the Creation of Dumbbell-Like Cu-Ag Nanostructures and Their Enhanced Catalytic Activity. Chemistry - A European Journal, 2012, 18, 9505-9510.	3.3	54
24	Reduced graphene oxide/silicon nanowire heterostructures with enhanced photoactivity and superior photoelectrochemical stability. Nano Research, 2015, 8, 2850-2858.	10.4	34
25	Self-catalyzed growth of InP/InSb axial nanowire heterostructures. Journal of Crystal Growth, 2011, 329, 6-11.	1.5	30
26	Graphene: An Emerging Electronic Material (Adv. Mater. 43/2012). Advanced Materials, 2012, 24, 5776-5776.	21.0	29
27	Ambipolar Barristors for Reconfigurable Logic Circuits. Nano Letters, 2017, 17, 1448-1454.	9.1	29
28	Self-catalyzed vapor-liquid-solid growth of InP _{1-x} Sb _x nanostructures. Journal of Crystal Growth, 2011, 319, 25-30.	1.5	25
29	Effect of precursor flux on compositional evolution in InP _{1-x} Sb _x nanowires grown via self-catalyzed vapor-liquid-solid process. Journal of Crystal Growth, 2011, 336, 14-19.	1.5	18
30	Metal-semiconductor transition in atomically thin Bi ₂ Sr ₂ Co ₂ O ₈ nanosheets. APL Materials, 2014, 2, .	5.1	8
31	Self-catalyzed vapor-liquid-solid growth of InP/InAsP core-shell nanopillars. Journal of Crystal Growth, 2011, 314, 34-38.	1.5	3